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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
09/667,596	09/22/2000	In Duk Song	2658-0190P	8013		
7:	590 06/04/2003					
Birch Stewart Kolasch & Birch LLP			EXAMINER			
P O Box 747 Falls Church, V	A 22040-0747		NGUYEN,	NGUYEN, HOAN C		
			ART UNIT	PAPER NUMBER		
			2871			
			DATE MAILED: 06/04/2003			

Please find below and/or attached an Office communication concerning this application or proceeding.

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,		Application No.	Applicant(s)	d-ip
-	Office And the O	09/667,596	YOO ET AL.	
Office Action Summary		Examin r	Art Unit	
		HOAN C. NGUYEN	2871	
Period fo	The MAILING DATE of this communication apor Reply	ppears n the cover sheet w	ith the correspondence add	ress
THE - Exte after - If the - If NO - Failu - Any	MAILING DATE OF THIS COMMUNICATION mesions of time may be available under the provisions of 37 CFR 1 SIX (6) MONTHS from the mailing date of this communication. Experiod for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period reply within the set or extended period for reply will, by stature to reply within the set or extended period for reply will, by stature ply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a ply within the statutory minimum of third will apply and will expire SIX (6) MON te. cause the application to become A	reply be timely filed ty (30) days will be considered timely. THS from the mailing date of this com	nmunication.
1)	Responsive to communication(s) filed on	·		
2a)⊠	This action is FINAL . 2b) ☐ T	his action is non-final.		
3) Dispositi	Since this application is in condition for allow closed in accordance with the practice unde ion of Claims	vance except for formal ma r <i>Ex parte Quayle</i> , 1935 C.	tters, prosecution as to the D. 11, 453 O.G. 213.	merits is
4)⊠	Claim(s) 1-31 is/are pending in the application	n.		
	4a) Of the above claim(s) is/are withdra	awn from consideration.		
5)	Claim(s) is/are allowed.			
6)⊠	Claim(s) <u>1-31</u> is/are rejected.			
7)	Claim(s) is/are objected to.			
8)□	Claim(s) are subject to restriction and/	or election requirement.		
	on Papers	,		
9) 🗌 .	The specification is objected to by the Examin	er.		
10) 🔲 -	The drawing(s) filed on is/are: a)□ acce	epted or b) objected to by t	he Examiner.	
	Applicant may not request that any objection to the	ne drawing(s) be held in abeya	ance. See 37 CFR 1.85(a).	
11) 🔲 🖯	The proposed drawing correction filed on	_ is: a)□ approved b)□ d	isapproved by the Examiner.	
	If approved, corrected drawings are required in re	eply to this Office action.		
12)[] 1	The oath or declaration is objected to by the Ex	xaminer.		
Priority u	nder 35 U.S.C. §§ 119 and 120			
13)	Acknowledgment is made of a claim for foreig	n priority under 35 U.S.C. §	§ 119(a)-(d) or (f).	
a)[☐ All b)☐ Some * c)☐ None of:			
	1. Certified copies of the priority documen	ts have been received.		
	2. Certified copies of the priority documen	ts have been received in A	pplication No	
	 Copies of the certified copies of the price application from the International But the attached detailed Office action for a list 	rity documents have been reau (PCT Rule 17.2(a)).	received in this National St	age
	cknowledgment is made of a claim for domest			pplication).
a)	☐ The translation of the foreign language procedure. The translation of the foreign language procedure.	ovisional application has be	en received.	sprioudion).
1) Notice 2) Notice 3) Inform	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s) _	5) Notice of Ir	Summary (PTO-413) Paper No(s). nformal Patent Application (PTO-1 .	.
.S. Patent and Tra PTO-326 (Rev		ction Summary	Part of Paper No. 18	

Application/Control Number: 09/667,596 Page 2

Art Unit: 2871

Response to Arguments

Applicant's arguments with respect to the amended claim 1, 21 and 23 have been considered but are most in view of the new ground(s) of rejection.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

1. Claims 1-31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Numano et al. (US6411346B1) in view of Kim et al. (US5995175A).

According to claims 1, 2, 7-10, 13, 16-19 and 21-22, Numano et al. teach (Figs. 14 and 15) a liquid crystal display (LCD) device comprising:

- a plurality of gate signal lines 2 formed on a substrate 1;
- a plurality of data/source lines 7 insulating from and intersecting the gate lines,
 the data lines and intersecting gate lines defining a plurality of cells, at least one
 cell including:
- a pixel electrode formed metallic pattern connecting the storage electrode to the drain electrode (claim 22).
- a thin film transistor (TFT) connecting to one of the data lines and one of gate lines defining the cell,

Application/Control Number: 09/667,596

Art Unit: 2871

a storage capacitor having storage electrode, which is formed on the gate line 2;

 a metallic pattern 8 including drain electrode of TFT and storage electrode of the storage capacitor and being electrically connected to the pixel electrode 12;
 wherein metallic pattern is spaced a predetermined distance from the data line via the gate insulating layer 4;

a protective layer 10 disposed between the pixel electrode and the metallic pattern,

wherein the pixel electrode is connected to a storage electrode part of metallic pattern via a first contact hole in the protective layer without including contact hole over a drain electrode (claims 7 and 8), and the drain electrode part has a smaller area than if the drain electrode part was electrically connected to the pixel electrode via a contact hole in the protective layer over the drain electrode (claim 9); the pixel electrode 139 has a larger aspect ratio than (expanding further into TFT region) if the drain electrode part was electrically connected to the pixel via a contact in the protective layer over the drain electrode (claim 10)

<u>or</u>

wherein, in the different forming process, the pixel electrode is connected to a drain electrode part of metallic pattern via a contact hole in the protective layer without concluding contact hole over a storage electrode, and the pixel electrode overlaps a gate lines less than if the protective layer included a contact hole over a storage electrode part of the metallic pattern.

Art Unit: 2871

According to claims 23, 25, 27-31, Numano et al. teach (Figs. 2-5, 14 and 15) a method of manufacturing a TFT substrate comprising:

- forming a plurality of gate signal lines 2 having gate electrode on a transparent/glass substrate 1;
- forming a gate insulating layer 4 on the gate electrode;
- forming a semiconductor layer 5/6 on the gate insulating layer;
- forming simultaneously a data/source line 7 having a source electrode 7, and a metallic pattern 8 including drain electrode part of TFT and storage electrode part of the storage capacitor in single layer;
- forming a semiconductor over at least a portion of one of the gate electrodes, at least a portion of one of the source electrode, and at least a portion of the drain electrode part in a single layer;
- forming a protecting film 10 over the entire surface with a first contact hole 175
 (exposing the storage electrode part of the metallic pattern (claim 27), and a second contact hole exposing the drain electrode part of the metallic pattern
 (claims 29 and 30)
- forming a pixel electrode 12 over the protective film;

However, Numano et al. fail to disclose a metallic pattern surrounding the cell and storage electrodes overlapped with a portion of a periphery of the pixel electrode.

Art Unit: 2871

Kim et al. disclose Kim et al. disclose (Figs. 7 and 11) a metallic pattern surrounding the cell and this metallic pattern forms storage electrodes overlapped with a portion of a periphery of the pixel electrode for increasing the aperture ratio and contrast ratio of the LCD as compared with the conventional LCD.

Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to further modify a liquid crystal display (LCD) device with a metallic pattern surrounding the cell and this metallic pattern forms storage electrodes overlapped with a portion of a periphery of the pixel electrode for increase the aperture ratio and contrast ratio of the LCD as compared with the conventional LCD.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

Application/Control Number: 09/667,596

Art Unit: 2871

Page 6

the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to HOAN C. NGUYEN whose telephone number is (703) 306-0472. The examiner can normally be reached on MONDAY-THURSDAY:8:00AM-4:30PM. Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0530.

HOAN C. NGUYEN

Examiner Art Unit 2871

chn May 30, 2003